

Acta Crystallographica Section E

Structure Reports

Online

ISSN 1600-5368

4-(Dimethylamino)benzaldehyde 4-ethylthiosemicarbazone

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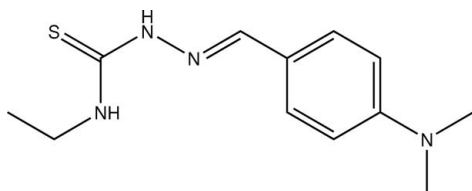
Received 30 October 2008; accepted 10 November 2008

Key indicators: single-crystal X-ray study; $T = 100$ K; mean $\sigma(\text{C}-\text{C}) = 0.001$ Å; disorder in main residue; R factor = 0.041; wR factor = 0.119; data-to-parameter ratio = 38.8.

The title thiosemicarbazone derivative, $\text{C}_{12}\text{H}_{18}\text{N}_4\text{S}$, features intramolecular $\text{N}-\text{H}\cdots\text{N}$ and $\text{C}-\text{H}\cdots\text{S}$ hydrogen bonds which generate $S(5)$ ring motifs. The dihedral angle between the benzene ring and the thiourea unit is $6.30(6)^\circ$ indicating planarity in the molecule. Intermolecular $\text{N}-\text{H}\cdots\text{S}$ hydrogen bonds generate dimers with an $R_2^2(8)$ ring motif. The methyl group of the N -ethyl residue is disordered and was refined with site occupancies of 0.521 (5) and 0.479 (5).

Related literature

For details of hydrogen-bond motifs, see: Bernstein *et al.* (1995). For related structures and applications see: Beraldo *et al.* (2001); Kayed *et al.* (2008); Valdes-Martinez *et al.* (1990).



Experimental

Crystal data

 $\text{C}_{12}\text{H}_{18}\text{N}_4\text{S}$ $M_r = 250.36$ Monoclinic, $P2_1/c$ $a = 9.3687(2)$ Å $b = 14.1872(3)$ Å $c = 10.2318(2)$ Å
 $\beta = 96.699(1)^\circ$
 $V = 1350.68(5)$ Å³
 $Z = 4$
 Mo $K\alpha$ radiation

 $\mu = 0.23$ mm⁻¹
 $T = 100(1)$ K
 $0.59 \times 0.36 \times 0.22$ mm

Data collection

 Bruker SMART APEXII CCD
 area-detector diffractometer
 Absorption correction: multi-scan
 (SADABS; Bruker, 2005)
 $T_{\min} = 0.879$, $T_{\max} = 0.953$

 30229 measured reflections
 6825 independent reflections
 5566 reflections with $I > 2\sigma(I)$
 $R_{\text{int}} = 0.036$

Refinement

 $R[F^2 > 2\sigma(F^2)] = 0.041$
 $wR(F^2) = 0.119$
 $S = 1.04$
 6825 reflections
 176 parameters

 H atoms treated by a mixture of
 independent and constrained
 refinement
 $\Delta\rho_{\text{max}} = 0.74$ e Å⁻³
 $\Delta\rho_{\text{min}} = -0.39$ e Å⁻³
Table 1
 Hydrogen-bond geometry (Å, °).

$D-H\cdots A$	$D-H$	$H\cdots A$	$D\cdots A$	$D-H\cdots A$
$\text{N3}-\text{H1N3}\cdots\text{S1}^1$	0.891 (15)	2.613 (15)	3.4910 (7)	168.8 (12)
$\text{N4}-\text{H1N4}\cdots\text{N2}$	0.885 (14)	2.193 (14)	2.6140 (10)	108.7 (11)
$\text{C9}-\text{H9B}\cdots\text{S1}$	0.96	2.78	3.1225 (9)	102

Symmetry code: (i) $-x, -y, -z$.

Data collection: APEX2 (Bruker, 2005); cell refinement: APEX2; data reduction: SAINT (Bruker, 2005); program(s) used to solve structure: SHELXTL (Sheldrick, 2008); program(s) used to refine structure: SHELXTL; molecular graphics: SHELXTL; software used to prepare material for publication: SHELXTL and PLATON (Spek, 2003).

We thank the Malaysian Government and Universiti Sains Malaysia for Science Fund grant No. 1001/229/PKIMIA/811055

Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: TK2323).

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supplementary materials

Acta Cryst. (2008). E64, o2353 [doi:10.1107/S1600536808037148]

4-(Dimethylamino)benzaldehyde 4-ethylthiosemicarbazone

A. Salhin, N. A. Razak and I. A. Rahman

Comment

Thiosemicarbazones have been a subject of extensive investigation (Kayed *et al.*, 2008) because of their ability to coordinate metal ions and their wide range of chemical and biological activities (Valdes-Martinez *et al.*, 1990 & Beraldo *et al.*, 2001). We present herein the X-ray structure of the title thiosemicarbazone derivative, (I).

Compound (I), Fig. 1, displays bond lengths and angles comparable to those in related structures (Beraldo *et al.*, 2001; Kayed *et al.*, 2008; Valdes-Martinez *et al.*, 1990). Intramolecular N—H \cdots N and C—H \cdots S contacts generate $S(5)$ ring motifs (Bernstein *et al.* 1995), Table 1. The dihedral angle between the phenyl ring and the thiourea unit is 6.30 (6) $^\circ$ which indicates the molecule is almost planar. Intermolecular N—H \cdots S hydrogen bonds generate $R_2^2(8)$ ring motifs to link molecules into dimers, Fig. 2. The methyl group of the *N*-ethyl residue is disordered and was refined with site occupancies of 0.521 (5)/0.479 (5).

Experimental

To 4-ethyl-3-thiosemicarbazide (ca. 0.119 g, 1 mmol) dissolved in ethanol (10 ml) was added dropwise an ethanol solution (5 ml) of 4-dimethylaminobenzaldehyde (0.149 g, 1 mmol) with continuous stirring. The solution was heated on a water bath for few minutes until the solution became clear. After cooling to room temperature, yellow crystals of (I) appeared.

Refinement

The N-bound H atoms were located from a difference Fourier map and refined freely. The remaining H were placed in their calculated positions in the riding model approximation with C—H 0.93–0.96 Å, and with $U(\text{H})$ set to 1.2–1.5 times $U_{\text{eq}}(\text{C})$. The presence of large peaks in the difference Fourier map near to the methyl group of (I) was suspected to be due to positional disorder of this fragment. The refined ratio of the site occupancy factors for the disorder parts were calculated to be 0.521 (5)/0.479 (5).

Figures

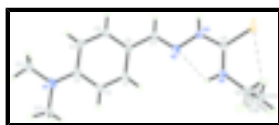


Fig. 1. The molecular structure of (I), showing 50% probability displacement ellipsoids and the atomic numbering. The intramolecular contacts are shown as dashed lines.

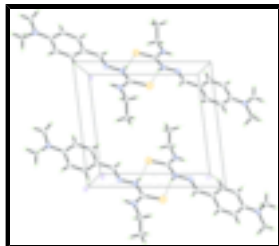


Fig. 2. Unit cell contents for the major component of (I), viewed down the b-axis showing dimers linked by $R_2^2(8)$ ring motifs. Intermolecular hydrogen bonds are shown as dashed lines.

4-(Dimethylamino)benzaldehyde 4-ethylthiosemicarbazone

Crystal data

$C_{12}H_{18}N_4S$

$M_r = 250.36$

Monoclinic, $P2_1/c$

Hall symbol: -P 2ybc

$a = 9.3687$ (2) Å

$b = 14.1872$ (3) Å

$c = 10.2318$ (2) Å

$\beta = 96.699$ (1)°

$V = 1350.68$ (5) Å³

$Z = 4$

$F_{000} = 536$

$D_x = 1.231$ Mg m⁻³

Mo $K\alpha$ radiation

$\lambda = 0.71073$ Å

Cell parameters from 9949 reflections

$\theta = 2.5$ – 39.5 °

$\mu = 0.23$ mm⁻¹

$T = 100$ (1) K

Block, yellow

$0.59 \times 0.36 \times 0.22$ mm

Data collection

Bruker SMART APEXII CCD area-detector diffractometer

Radiation source: fine-focus sealed tube

Monochromator: graphite

$T = 100$ (1) K

φ and ω scans

Absorption correction: multi-scan (SADABS; Bruker, 2005)

$T_{\min} = 0.879$, $T_{\max} = 0.953$

30229 measured reflections

6825 independent reflections

5566 reflections with $I > 2\sigma(I)$

$R_{\text{int}} = 0.036$

$\theta_{\max} = 37.0$ °

$\theta_{\min} = 2.2$ °

$h = -15$ → 13

$k = -24$ → 20

$l = -15$ → 17

Refinement

Refinement on F^2

Least-squares matrix: full

$R[F^2 > 2\sigma(F^2)] = 0.041$

$wR(F^2) = 0.119$

$S = 1.04$

Secondary atom site location: difference Fourier map

Hydrogen site location: inferred from neighbouring sites

H atoms treated by a mixture of independent and constrained refinement

$w = 1/[\sigma^2(F_o^2) + (0.0651P)^2 + 0.2126P]$

where $P = (F_o^2 + 2F_c^2)/3$

$(\Delta/\sigma)_{\max} = 0.001$

6825 reflections $\Delta\rho_{\max} = 0.74 \text{ e } \text{\AA}^{-3}$
 176 parameters $\Delta\rho_{\min} = -0.39 \text{ e } \text{\AA}^{-3}$
 Primary atom site location: structure-invariant direct methods Extinction correction: none

Special details

Experimental. The low-temperature data was collected with the Oxford Cyrosystem Cobra low-temperature attachment.

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R -factor wR and goodness of fit S are based on F^2 , conventional R -factors R are based on F , with F set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating R -factors(gt) *etc.* and is not relevant to the choice of reflections for refinement. R -factors based on F^2 are statistically about twice as large as those based on F , and R -factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\AA^2)

	<i>x</i>	<i>y</i>	<i>z</i>	$U_{\text{iso}}^*/U_{\text{eq}}$	Occ. (<1)
S1	0.16244 (2)	0.114147 (15)	-0.039117 (18)	0.01984 (6)	
N1	-0.30894 (9)	0.10562 (6)	0.82869 (8)	0.02457 (15)	
N2	-0.01025 (7)	0.10572 (5)	0.29168 (6)	0.01690 (12)	
N3	0.02454 (7)	0.08428 (5)	0.16770 (6)	0.01731 (12)	
N4	0.18487 (7)	0.20579 (5)	0.19197 (7)	0.01837 (12)	
C1	-0.09174 (8)	0.13272 (6)	0.55310 (7)	0.01760 (13)	
H1A	-0.0138	0.1680	0.5323	0.021*	
C2	-0.14161 (8)	0.14561 (6)	0.67363 (7)	0.01834 (13)	
H2A	-0.0977	0.1900	0.7319	0.022*	
C3	-0.25861 (8)	0.09230 (6)	0.70986 (7)	0.01732 (13)	
C4	-0.32165 (9)	0.02550 (6)	0.61854 (8)	0.01997 (14)	
H4A	-0.3979	-0.0113	0.6396	0.024*	
C5	-0.27073 (9)	0.01429 (6)	0.49756 (8)	0.01935 (14)	
H5A	-0.3142	-0.0300	0.4388	0.023*	
C6	-0.15624 (8)	0.06743 (5)	0.46132 (7)	0.01601 (12)	
C7	-0.10836 (8)	0.05380 (6)	0.33282 (7)	0.01745 (13)	
H7A	-0.1498	0.0062	0.2786	0.021*	
C8	0.12430 (8)	0.13664 (6)	0.11598 (7)	0.01551 (12)	
C9	0.29288 (10)	0.27026 (6)	0.15428 (9)	0.02484 (16)	
H9A	0.2867	0.3279	0.2024	0.030*	0.521 (5)
H9B	0.2702	0.2848	0.0626	0.030*	0.521 (5)
H9C	0.2877	0.3291	0.1999	0.030*	0.479 (5)
H9D	0.2767	0.2823	0.0614	0.030*	0.479 (5)
C10A	0.4427 (11)	0.2356 (8)	0.1674 (8)	0.0361 (12)	0.521 (5)
H10A	0.5045	0.2841	0.1403	0.054*	0.521 (5)
H10B	0.4486	0.1810	0.1128	0.054*	0.521 (5)
H10C	0.4724	0.2192	0.2575	0.054*	0.521 (5)

supplementary materials

C10B	0.4457 (14)	0.2268 (10)	0.1992 (9)	0.0394 (15)	0.479 (5)
H10D	0.4558	0.2160	0.2925	0.059*	0.479 (5)
H10E	0.5188	0.2698	0.1782	0.059*	0.479 (5)
H10F	0.4554	0.1681	0.1544	0.059*	0.479 (5)
C11	-0.43497 (11)	0.05588 (7)	0.86103 (10)	0.02942 (19)	
H11A	-0.5107	0.0619	0.7898	0.044*	
H11B	-0.4657	0.0823	0.9395	0.044*	
H11C	-0.4121	-0.0096	0.8753	0.044*	
C12	-0.24779 (10)	0.17816 (8)	0.91858 (9)	0.02932 (19)	
H12A	-0.1452	0.1710	0.9325	0.044*	
H12B	-0.2864	0.1722	1.0011	0.044*	
H12C	-0.2713	0.2392	0.8815	0.044*	
H1N4	0.1570 (14)	0.2111 (10)	0.2711 (14)	0.032 (3)*	
H1N3	-0.0171 (15)	0.0353 (11)	0.1243 (14)	0.035 (4)*	

Atomic displacement parameters (\AA^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
S1	0.02294 (10)	0.02210 (11)	0.01529 (9)	-0.00401 (7)	0.00569 (6)	-0.00261 (6)
N1	0.0315 (4)	0.0243 (4)	0.0202 (3)	-0.0016 (3)	0.0121 (3)	-0.0011 (2)
N2	0.0198 (3)	0.0176 (3)	0.0137 (2)	-0.0005 (2)	0.0038 (2)	-0.0006 (2)
N3	0.0206 (3)	0.0178 (3)	0.0141 (2)	-0.0036 (2)	0.0043 (2)	-0.0018 (2)
N4	0.0212 (3)	0.0178 (3)	0.0166 (3)	-0.0039 (2)	0.0044 (2)	-0.0022 (2)
C1	0.0179 (3)	0.0185 (3)	0.0166 (3)	-0.0026 (2)	0.0028 (2)	-0.0005 (2)
C2	0.0199 (3)	0.0199 (3)	0.0152 (3)	-0.0015 (3)	0.0024 (2)	-0.0015 (2)
C3	0.0205 (3)	0.0157 (3)	0.0166 (3)	0.0026 (2)	0.0057 (2)	0.0018 (2)
C4	0.0215 (3)	0.0171 (3)	0.0226 (3)	-0.0025 (3)	0.0082 (3)	-0.0007 (3)
C5	0.0213 (3)	0.0167 (3)	0.0208 (3)	-0.0040 (2)	0.0060 (2)	-0.0031 (2)
C6	0.0181 (3)	0.0149 (3)	0.0153 (3)	-0.0008 (2)	0.0032 (2)	-0.0001 (2)
C7	0.0199 (3)	0.0168 (3)	0.0160 (3)	-0.0013 (2)	0.0034 (2)	-0.0013 (2)
C8	0.0162 (3)	0.0156 (3)	0.0148 (3)	0.0000 (2)	0.0017 (2)	0.0010 (2)
C9	0.0294 (4)	0.0199 (4)	0.0269 (4)	-0.0092 (3)	0.0107 (3)	-0.0057 (3)
C10A	0.0211 (12)	0.032 (2)	0.057 (3)	-0.0087 (13)	0.011 (2)	-0.015 (2)
C10B	0.0265 (14)	0.036 (2)	0.057 (4)	-0.0113 (14)	0.009 (3)	-0.011 (3)
C11	0.0374 (5)	0.0252 (4)	0.0291 (4)	-0.0005 (4)	0.0190 (4)	0.0033 (3)
C12	0.0275 (4)	0.0409 (6)	0.0199 (3)	0.0028 (4)	0.0037 (3)	-0.0083 (3)

Geometric parameters (\AA , $^\circ$)

S1—C8	1.6971 (7)	C6—C7	1.4508 (10)
N1—C3	1.3675 (10)	C7—H7A	0.9300
N1—C11	1.4466 (12)	C9—C10A	1.479 (10)
N1—C12	1.4528 (13)	C9—C10B	1.577 (13)
N2—C7	1.2864 (10)	C9—H9A	0.9600
N2—N3	1.3800 (9)	C9—H9B	0.9600
N3—C8	1.3494 (10)	C9—H9C	0.9600
N3—H1N3	0.890 (15)	C9—H9D	0.9600
N4—C8	1.3365 (10)	C10A—H10A	0.9600
N4—C9	1.4492 (11)	C10A—H10B	0.9600

N4—H1N4	0.883 (14)	C10A—H10C	0.9600
C1—C2	1.3810 (10)	C10B—H10D	0.9600
C1—C6	1.4045 (11)	C10B—H10E	0.9600
C1—H1A	0.9300	C10B—H10F	0.9600
C2—C3	1.4162 (11)	C11—H11A	0.9600
C2—H2A	0.9300	C11—H11B	0.9600
C3—C4	1.4111 (12)	C11—H11C	0.9600
C4—C5	1.3867 (11)	C12—H12A	0.9600
C4—H4A	0.9300	C12—H12B	0.9600
C5—C6	1.3961 (11)	C12—H12C	0.9600
C5—H5A	0.9300		
C3—N1—C11	120.75 (8)	C10A—C9—H9A	110.5
C3—N1—C12	120.62 (8)	C10B—C9—H9A	106.9
C11—N1—C12	118.22 (7)	N4—C9—H9B	108.3
C7—N2—N3	115.40 (7)	C10A—C9—H9B	105.1
C8—N3—N2	119.20 (7)	C10B—C9—H9B	117.3
C8—N3—H1N3	121.2 (9)	H9A—C9—H9B	107.4
N2—N3—H1N3	119.6 (9)	N4—C9—H9C	110.0
C8—N4—C9	124.80 (7)	C10A—C9—H9C	110.3
C8—N4—H1N4	116.4 (9)	C10B—C9—H9C	107.1
C9—N4—H1N4	118.7 (9)	H9B—C9—H9C	105.7
C2—C1—C6	121.36 (7)	N4—C9—H9D	110.0
C2—C1—H1A	119.3	C10A—C9—H9D	100.8
C6—C1—H1A	119.3	C10B—C9—H9D	113.0
C1—C2—C3	121.05 (7)	H9A—C9—H9D	110.1
C1—C2—H2A	119.5	H9C—C9—H9D	108.4
C3—C2—H2A	119.5	C9—C10A—H10A	109.5
N1—C3—C4	121.35 (7)	C9—C10A—H10B	109.5
N1—C3—C2	121.11 (7)	C9—C10A—H10C	109.5
C4—C3—C2	117.53 (7)	C9—C10B—H10D	109.5
C5—C4—C3	120.47 (7)	C9—C10B—H10E	109.5
C5—C4—H4A	119.8	H10D—C10B—H10E	109.5
C3—C4—H4A	119.8	C9—C10B—H10F	109.5
C4—C5—C6	122.02 (7)	H10D—C10B—H10F	109.5
C4—C5—H5A	119.0	H10E—C10B—H10F	109.5
C6—C5—H5A	119.0	N1—C11—H11A	109.5
C5—C6—C1	117.54 (7)	N1—C11—H11B	109.5
C5—C6—C7	119.81 (7)	H11A—C11—H11B	109.5
C1—C6—C7	122.65 (7)	N1—C11—H11C	109.5
N2—C7—C6	121.90 (7)	H11A—C11—H11C	109.5
N2—C7—H7A	119.1	H11B—C11—H11C	109.5
C6—C7—H7A	119.1	N1—C12—H12A	109.5
N4—C8—N3	116.26 (6)	N1—C12—H12B	109.5
N4—C8—S1	124.10 (6)	H12A—C12—H12B	109.5
N3—C8—S1	119.62 (6)	N1—C12—H12C	109.5
N4—C9—C10A	116.8 (4)	H12A—C12—H12C	109.5
N4—C9—C10B	108.3 (4)	H12B—C12—H12C	109.5
N4—C9—H9A	108.4		

supplementary materials

C7—N2—N3—C8	178.60 (7)	C4—C5—C6—C7	-179.19 (8)
C6—C1—C2—C3	0.93 (12)	C2—C1—C6—C5	-1.47 (12)
C11—N1—C3—C4	-4.17 (13)	C2—C1—C6—C7	178.59 (8)
C12—N1—C3—C4	-176.68 (8)	N3—N2—C7—C6	179.78 (7)
C11—N1—C3—C2	175.45 (8)	C5—C6—C7—N2	174.99 (8)
C12—N1—C3—C2	2.93 (13)	C1—C6—C7—N2	-5.08 (12)
C1—C2—C3—N1	-179.39 (8)	C9—N4—C8—N3	-179.39 (8)
C1—C2—C3—C4	0.24 (12)	C9—N4—C8—S1	-1.06 (12)
N1—C3—C4—C5	178.80 (8)	N2—N3—C8—N4	1.21 (11)
C2—C3—C4—C5	-0.82 (12)	N2—N3—C8—S1	-177.20 (5)
C3—C4—C5—C6	0.26 (13)	C8—N4—C9—C10A	-81.0 (4)
C4—C5—C6—C1	0.88 (12)	C8—N4—C9—C10B	-90.9 (4)

Hydrogen-bond geometry (\AA , $^\circ$)

<i>D</i> —H \cdots <i>A</i>	<i>D</i> —H	H \cdots <i>A</i>	<i>D</i> \cdots <i>A</i>	<i>D</i> —H \cdots <i>A</i>
N3—H1N3 \cdots S1 ⁱ	0.891 (15)	2.613 (15)	3.4910 (7)	168.8 (12)
N4—H1N4 \cdots N2	0.885 (14)	2.193 (14)	2.6140 (10)	108.7 (11)
C9—H9B \cdots S1	0.96	2.78	3.1225 (9)	102

Symmetry codes: (i) $-x, -y, -z$.

Fig. 1

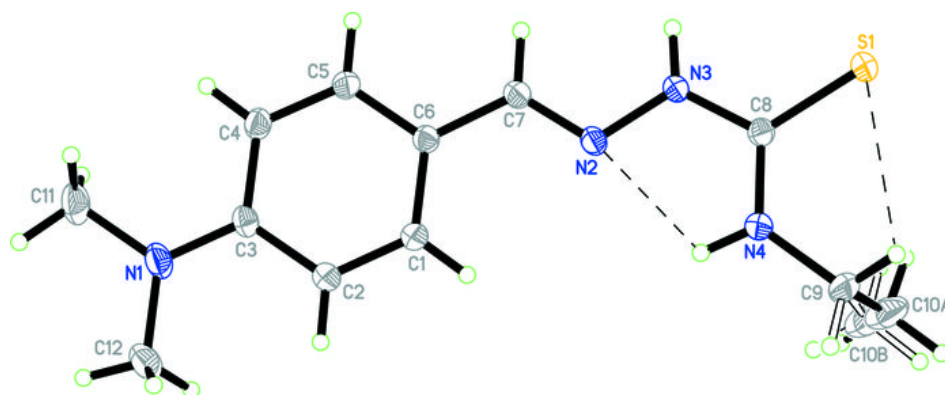


Fig. 2

